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SPECIFICATION

PRODUCT NAME: VOLTAGE CONTROLLED CRYSTAL OSCILLATOR

TYPE:

CSX-750V

FREQUENCY:

MHz

PARTS NO.:

CITIZEN WATCH CO., LTD. 1-12, Honcho 6-chome, Tanashi-shi, Tokyo 188-8511 Japan

Oscillator Technical section Crystal Devices Div. Telephone: 0424-68-4572 Fax : 0424-68-4666

PRODUCTS MARKETING GROUP Telephone: 0424-67-6214 Telex:2822-471/ Fax: 0424-67-8503

APPROVED	CHECKED	PREPARED

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I. SCOPE

This specification relates to the voltage controlled crystal oscillator to be supplied by CITIZEN WATCH CO., LTD. (following as CITIZEN) .

NOTICE

1.If something that is ambiguously defined or undefined in this specification happened, the customer and CITIZEN would discuss and take necessary steps by mutual consent.

- 2. Product test data can't be attached to this specification.
- 3. This product is not authorized for use as critical component in life support devices or systems.

II. SPECIFICATION

1. ABSOLUTE MAXIMUM RATING

Parameter		CSX750VB/CSX750VC
Supply Voltage	Vmax	-0.5V to +7.0V
Storage Temperature	Tstg	-45°C to +90°C
Output Current	lout	10mA Max.
Input Control Voltage	Vc_m	-0.5V to Vdd +0.5V
Solder Heat Resistance	Tsol	Max.240°C x Max.10 seconds x 2times
Of The Outer Lead		Max.200°C x Max. 3 minutes

2. OPERATING RANGE

Parameter		CSX750VB CSX750VC	
Supply Voltage Vdd		3.3V±5% 5.0V±10%	
Operating Temperature	Topr	-10°C to 70°C or -40°C to 85°C	
Input Control Voltage	Vc	0.0V to Vdd	
Output Load	CL	30pF Max.	

3. FREQUENCY CHARACTERISTICS

Parameter		CSX750VB CSX750VC		
Stability (note1)	dF0	±50ppm Max.		
Pullability (note2)	Fpull	±90ppm Min.	±100ppm Min.	
Linearity	Ldev	±15% Max.	±10% Max.	
Modulation Band Width	Fmod	10kHz Min.		

note1) Frequency Stability includes initial tolerance, temperature characteristics, input voltage characteristics, load characteristics, shock, vibration, reflow and 1st year aging. note2) Vc=1.65V±1.65V (CSX750VB) Vc=2.5V±2.0V (CSX750VC)

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4. ELECTRICAL CHARACTERISTICS (Ta=25°C load=30pF Vc=Vdd/2)

Parameter		Conditions	CSX750VB CSX750V	
Start Up Time (note)	tosc		4msec Max.	
Power Supply Current	ldd	No Load	11mA Max.	30mA Max.
Disable Current	linh	No Load	5mA Max.	20mA Max.
Rise Time	tr	20% to 80%Vdd	5ns Max.	
Fall Time	tf	80% to 20%Vdd	5ns Max.	
Duty Cycle	duty	50%Vdd	45% to 55%	
Output HIGH Voltage	Voh	loh = -0.8mA	Vdd-0.4V Min.	
Output LOW Voltage	Vol	lol = 3.2mA	0.4V Max.	
OE Input HIGH Voltage	Vih		Vdd x 0.7 Min.	
OE Input LOW Voltage	Vil		Vdd x 0.3 Max.	
Output Disable Time	tpxz	See 5.	100ns	s Max.
Output Enable Time	tpzx		100ns Max.	

note) Vc must be kept ground level or left open when starting up.

5. THREE STATE OUTPUT OPERATION

OE Input	Clock Output	
HIGH or OPEN	Active	enable
LOW	High impedance	disable





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8. ENVIRONMENTAL AND MECHANICAL CHARACTERISTICS The following are our reliability test conditions.

Item	Conditions
Shock	MIL-STD-883E 2002.3B
Vibration	MIL-STD-883E 2007.2A
Gross Leak	Leak rate less than 50ppm atm cc /sec of Air
Fine Leak	Leak rate less than 0.01ppm atm cc /sec of Herium









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V. NOTES 1. HANDLING (ELECTROS This device i to prevent d	CATIC DISCHARGES) s made with CMOS circuitry. Plea amage due to electrical static disc	ase take precauti charge.	ions
(SHOCK REL This device of An automation in case that the your machine	IABILITY) contains a quartz crystal, so pleas c insersion is available, however, oo much shock or vibration is give e condition in advance.	e do not give too the internal quar en by machine c	o much shock or vibration. tz crystal might be damaged ondition. Be sure to check
(CLEANING) Since, deper to the Crysta company's c	nding on the cleaning conditions,t I Osillator,do not fail to test and c leaning conditions.	here is a possibi onfirm the result	lity of damage being caused s beforehand,using your
(TEMPERAT We recomen When this de condensation As with other	URE AND HUMIDITY) d to store and use device under r evice is used in high humidity app า. r IC's, please take precautions to	normal temperatu lications, there is prevent condens	ure and humidity. s a potential problem with sation.
2. CIRCUIT E (POWER LIN We recomen operation an VDD and GN	DESIGNS ES) d placing a 0.01 to 0.1uF capacit d protect against power line ripple ID pattern should be as wide as p	or between VDD e . possible.	and GND to obtain stable
(OE INPUT L When OE pir	INE) ו is not used, please connect it to	VDD.	
(OUTPUT LIN As a long ou is as short as	NE) tput line may cause irregular outp s possible, and also keep high lev	out, please take c /el signal source	care to design that output line away from this device.
(STARTING I Vc must be k	JP) ept ground level or left open whe	n starting up.	